

Optimum power handling
 Low on-state and switching losses
 Designed for traction and industrial applications

Rectifier Stud Diode Type D175-400-18

| | | | | | | | | | | | | | | | |
|---------------------------------|------------|-----|-----|-----|-----|-----|-----------|------|-------------|------|------|------|------|------|------|
| Mean on-state current | | | | | | | I_{FAV} | | 400 A | | | | | | |
| Repetitive peak reverse voltage | | | | | | | V_{RRM} | | 300 ÷ 1800V | | | | | | |
| V_{RRM} , V | 300 | 400 | 500 | 600 | 700 | 800 | 900 | 1000 | 1100 | 1200 | 1300 | 1400 | 1500 | 1600 | 1800 |
| Voltage code | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | 12 | 13 | 14 | 15 | 16 | 18 |
| T_j , °C | - 60 ÷ 190 | | | | | | | | | | | | | | |

MAXIMUM ALLOWABLE RATINGS

| Symbols and parameters | | Units | Values | Test conditions | |
|------------------------|--------------------------------------|-------------------|---------------------|---|---|
| ON-STATE | | | | | |
| I_{FAV} | Average forward current | A | 400 544 | $T_c=144$ °C; $T_c=120$ °C; 180° half-sine wave; 50 Hz | |
| I_{FRMS} | RMS forward current | A | 628 | $T_c=144$ °C; 180° half-sine wave; 50 Hz | |
| I_{FSM} | Surge forward current | kA | 13.0 16.0 | $T_j=T_{jmax}$ $T_j=25$ °C | 180° half-sine wave; $t_p=10$ ms; single pulse; $V_R=0$ V; |
| | | | 14.0 17.0 | $T_j=T_{jmax}$ $T_j=25$ °C | 180° half-sine wave; $t_p=8.3$ ms; single pulse; $V_R=0$ V; |
| I^2t | Safety factor | $A^2s \cdot 10^3$ | 840 1280 | $T_j=T_{jmax}$ $T_j=25$ °C | 180° half-sine wave; $t_p=10$ ms; single pulse; $V_R=0$ V; |
| | | | 810 1190 | $T_j=T_{jmax}$ $T_j=25$ °C | 180° half-sine wave; $t_p=8.3$ ms; single pulse; $V_R=0$ V; |
| BLOCKING | | | | | |
| V_{RRM} | Repetitive peak reverse voltages | V | 300÷1800 | $T_{jmin} < T_j < T_{jmax}$; 180° half-sine wave; 50 Hz; | |
| V_{RSM} | Non-repetitive peak reverse voltages | V | 350÷2080 | $T_{jmin} < T_j < T_{jmax}$; 180° half-sine wave; single pulse; | |
| V_R | Reverse continuous voltages | V | $0.6 \cdot V_{RRM}$ | $T_j=T_{jmax}$; | |
| THERMAL | | | | | |
| T_{stg} | Storage temperature | °C | - 60 ÷ 50 | | |
| T_j | Operating junction temperature | °C | - 60 ÷ 190 | | |
| MECHANICAL | | | | | |
| F | Mounting force | kN | 1.5 ÷ 2.5 | | |
| a | Acceleration | m/s^2 | 100 | | |

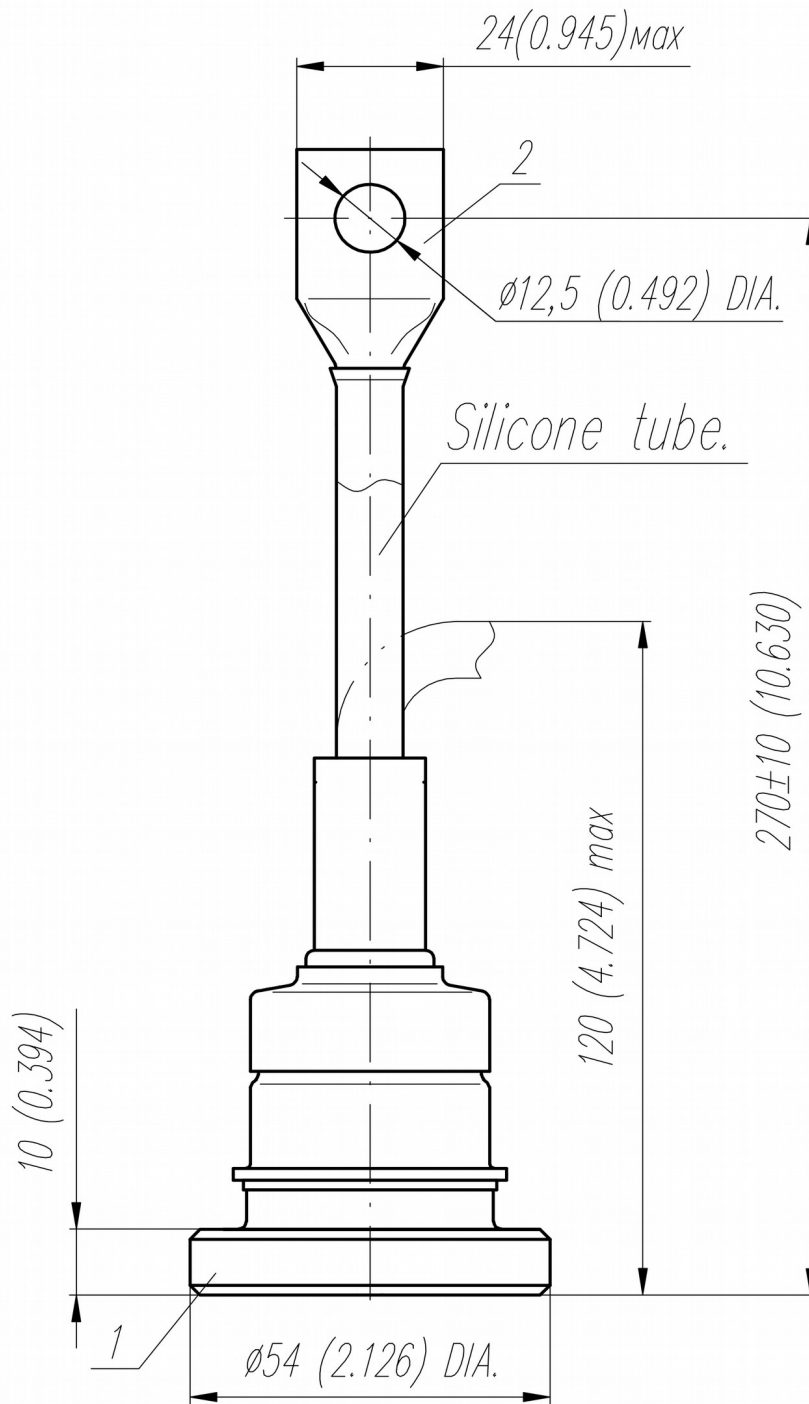
CHARACTERISTICS

| Symbols and parameters | | Units | Values | Conditions |
|------------------------|---|---------------------------|-----------------|---|
| ON-STATE | | | | |
| V_{FM} | Peak forward voltage, max | V | 1.45 | $T_j=25\text{ }^\circ\text{C}; I_{FM}=1256\text{ A}$ |
| $V_{F(TO)}$ | Forward threshold voltage, max | V | 0.802 | $T_j=T_{j,max};$ $0.5\pi I_{FAV} < I_T < 1.5\pi I_{FAV}$ |
| r_T | Forward slope resistance, max | m Ω | 0.534 | |
| BLOCKING | | | | |
| I_{RRM} | Repetitive peak reverse current, max | mA | 40 | $T_j=T_{j,max};$ $V_R=V_{RRM}$ |
| SWITCHING | | | | |
| Q_{rr} | Total recovered charge, max | μC | 1500 | $T_j=T_{j,max}; I_{TM}=400\text{ A};$ $di_R/dt=-10\text{ A}/\mu\text{s};$ $V_R=100\text{ V};$ |
| t_{rr} | Reverse recovery time, max | μs | 22 | |
| I_{rrM} | Peak reverse recovery current, max | A | 135 | |
| THERMAL | | | | |
| R_{thjc} | Thermal resistance, junction to case, max | $^\circ\text{C}/\text{W}$ | 0.085 | Direct current |
| MECHANICAL | | | | |
| w | Weight, max | g | 500 | |
| D_s | Surface creepage distance | mm (inch) | 12.4 (4.882) | |
| D_a | Air strike distance | mm (inch) | 12.4 (4.882) | |

PART NUMBERING GUIDE

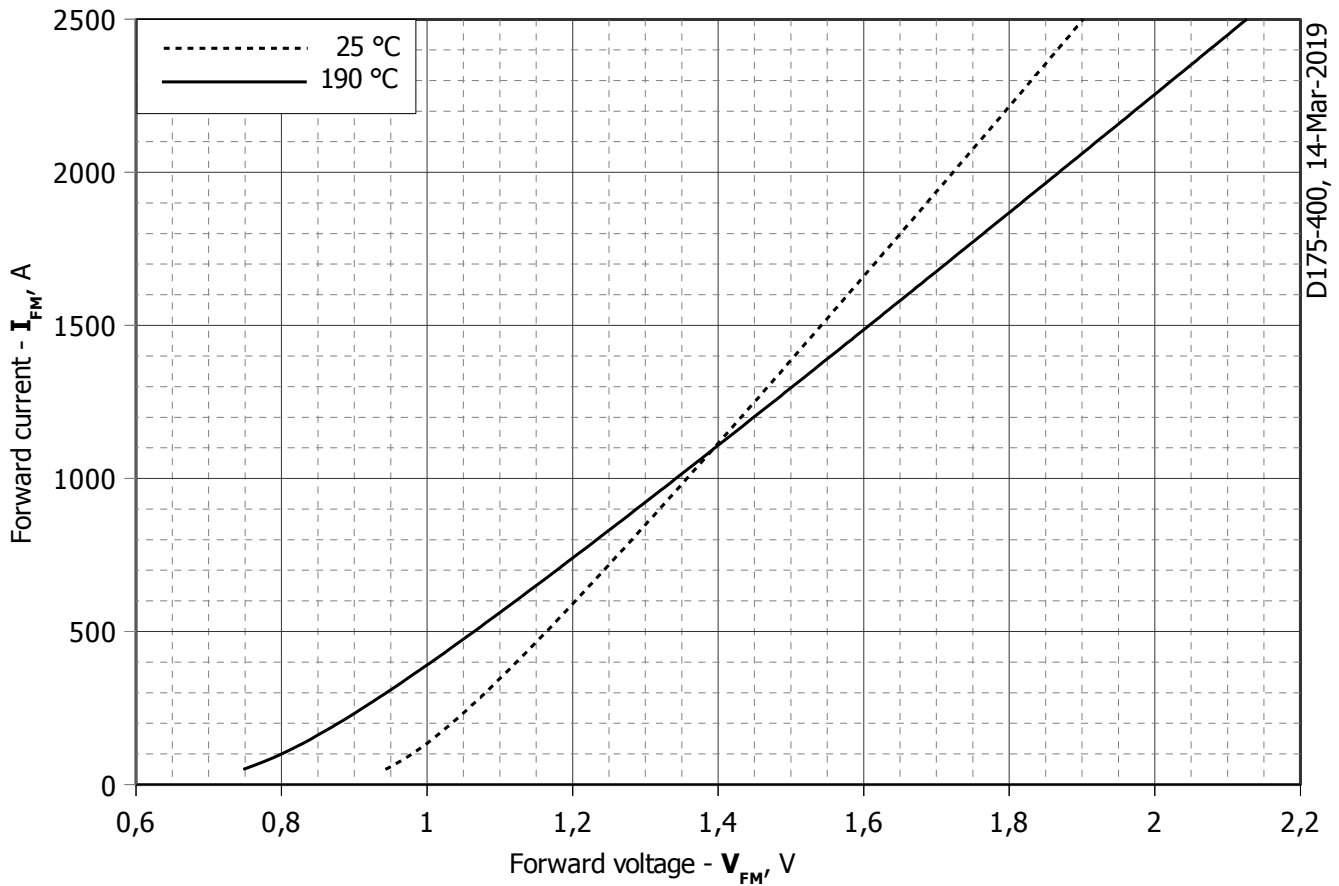
| | | | | | |
|---|-----|-----|---|----|---|
| D | 175 | 400 | | 18 | N |
| 1 | 2 | 3 | 4 | 5 | 6 |

1. D — Rectifier Diode
2. Design version
3. Average forward current, A
4. Polarity: X – Cathode to Stud; Anode to Stud – no symbol
5. Voltage code
6. Ambient conditions: N – normal; T – tropical



| Polarity | | Example of code designation | Reference designation | Colors | |
|----------|---------------|-----------------------------|-----------------------|--------|----------|
| | | | | Anode | Cathode |
| Normal | Anode to stud | D175-400-18 | | - | Red tube |

All dimensions in millimeters (inches)



D175-400, 14-Mar-2019

Fig 1 – Forward characteristics of Limit device

$$V_F = A + B \cdot i_F + C \cdot \ln(i_F + 1) + D \cdot \sqrt{i_F}$$

| | Coefficients for max curves | |
|----------|-----------------------------|-------------------------|
| | $T_j = 25^\circ\text{C}$ | $T_j = T_{j\text{max}}$ |
| A | 0,81586000 | 0,56549000 |
| B | 0,00034291 | 0,00049665 |
| C | 0,02739000 | 0,03970700 |
| D | 0,00028787 | 0,00017268 |

Forward characteristic model (see Fig. 1).

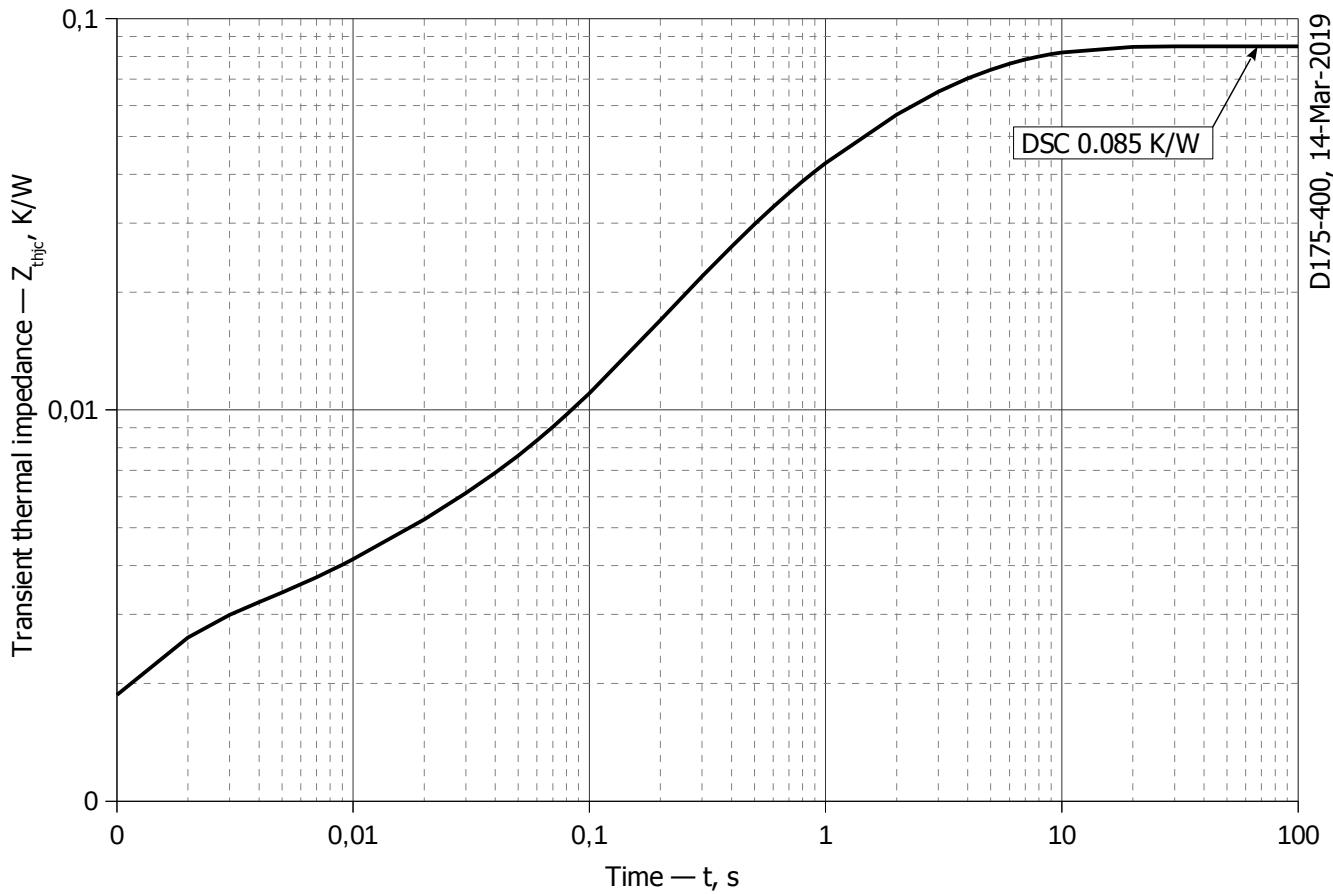


Fig 2 – Transient thermal impedance Z_{thjc} vs. time t

Analytical function for Transient thermal impedance junction to case Z_{thjc} for DC:

$$Z_{thjc} = \sum_{i=1}^n R_i \left(1 - e^{-\frac{t}{\tau_i}} \right)$$

Where $i = 1$ to n , n is the number of terms in the series.

t = Duration of heating pulse in seconds.

Z_{thjc} = Thermal resistance at time t .

R_i = Amplitude of p_{th} term.

τ_i = Time constant of r_{th} term.

DC

| i | 1 | 2 | 3 | 4 | 5 | 6 |
|-------------------------------|----------|----------|----------|----------|-----------|----------|
| R_i, K/W | 0.023357 | 0.02733 | 0.01495 | 0.001445 | 0.002488 | 0.01543 |
| τ_i, s | 4.627 | 2.249 | 0.3406 | 0.01043 | 0.0009112 | 0.9081 |

Transient thermal impedance junction to case Z_{thjc} model (see Fig. 2)

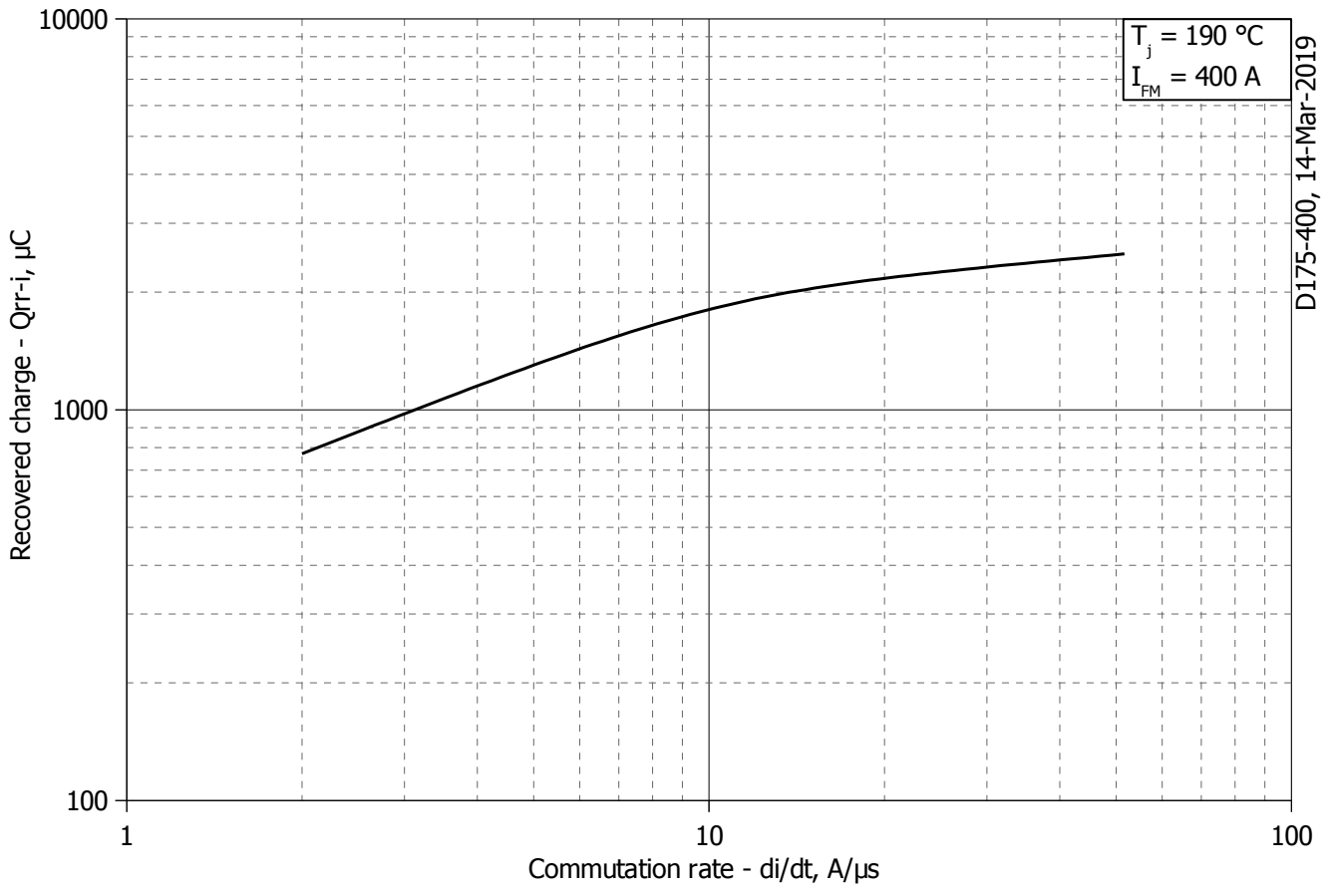


Fig 3 – Maximum recovered charge Q_{rr-i} (integral) vs. commutation rate di_R/dt

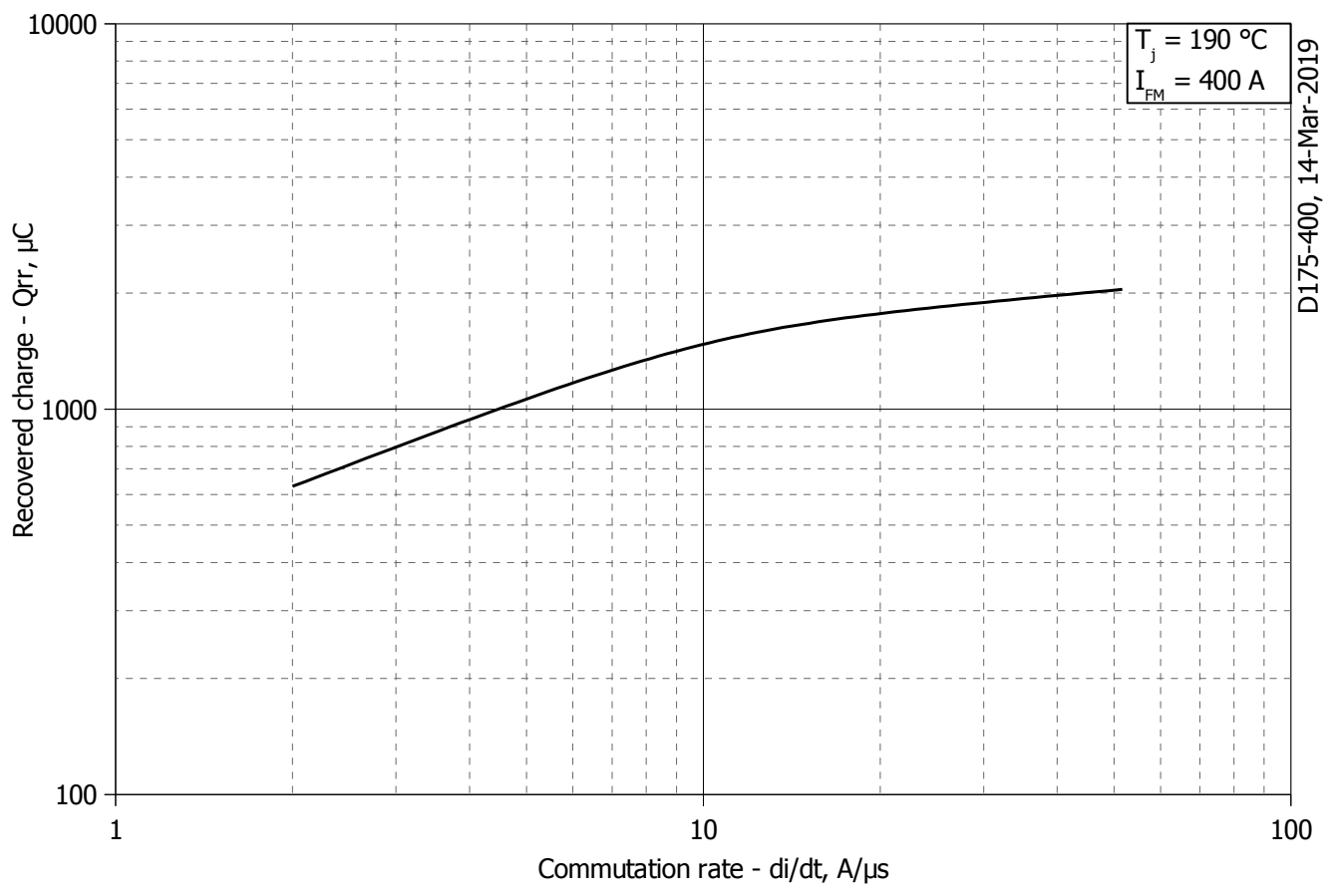


Fig 4 – Maximum recovered charge Q_{rr} vs. commutation rate di_R/dt (25% chord)

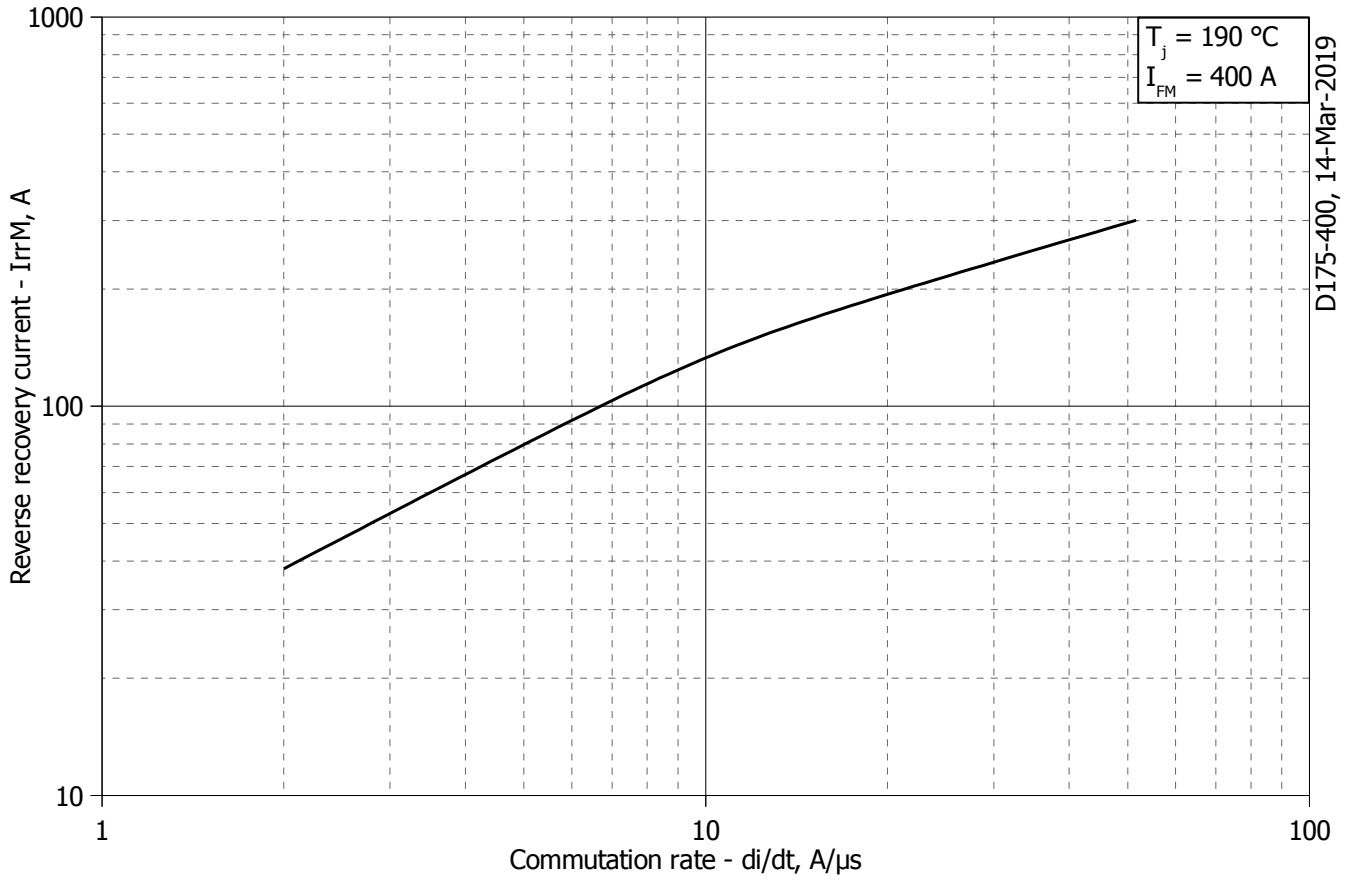


Fig 5 – Maximum reverse recovery current I_{rrM} vs. commutation rate di_R/dt

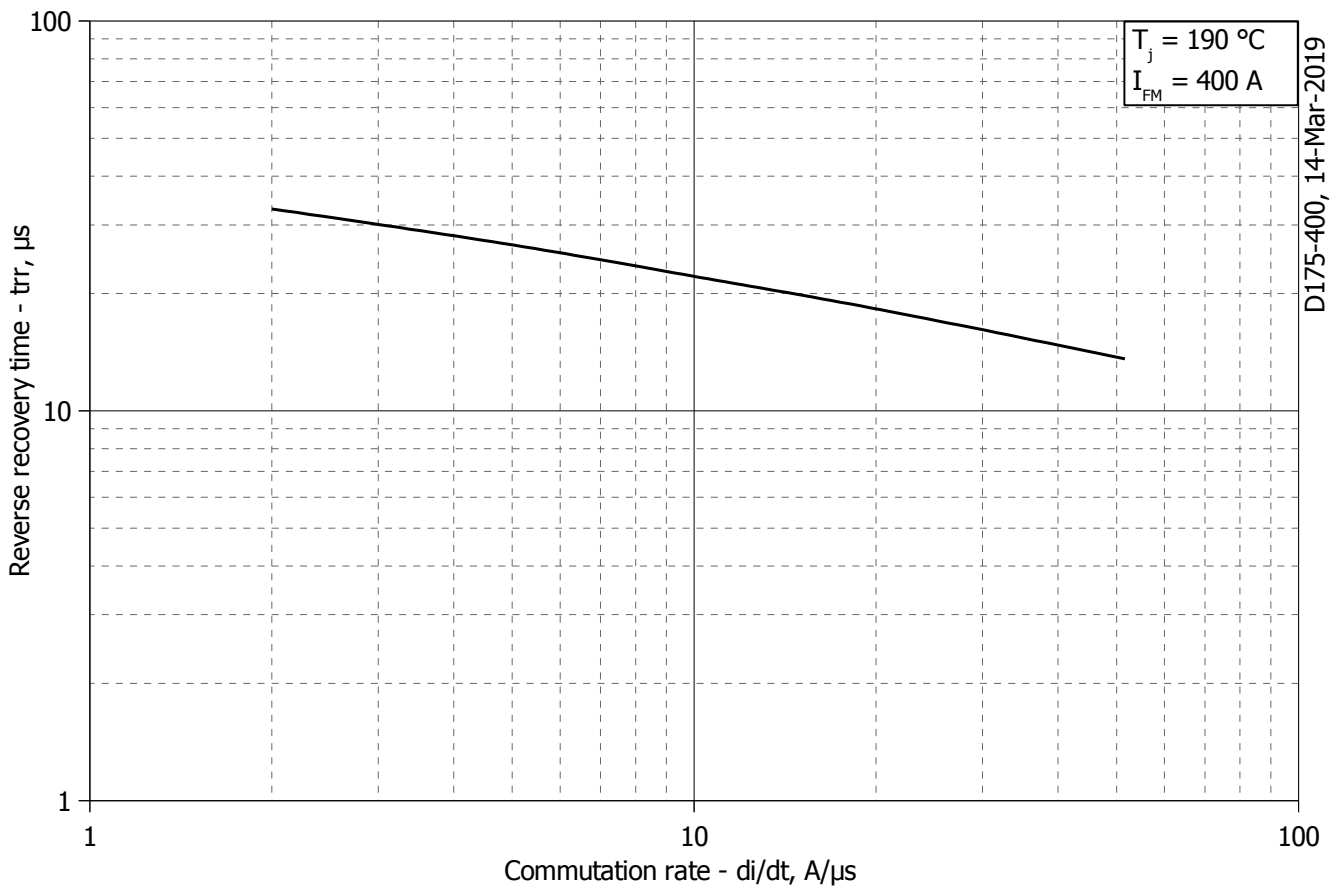


Fig 6 – Maximum recovery time t_{tr} vs. commutation rate di_R/dt (25% chord)

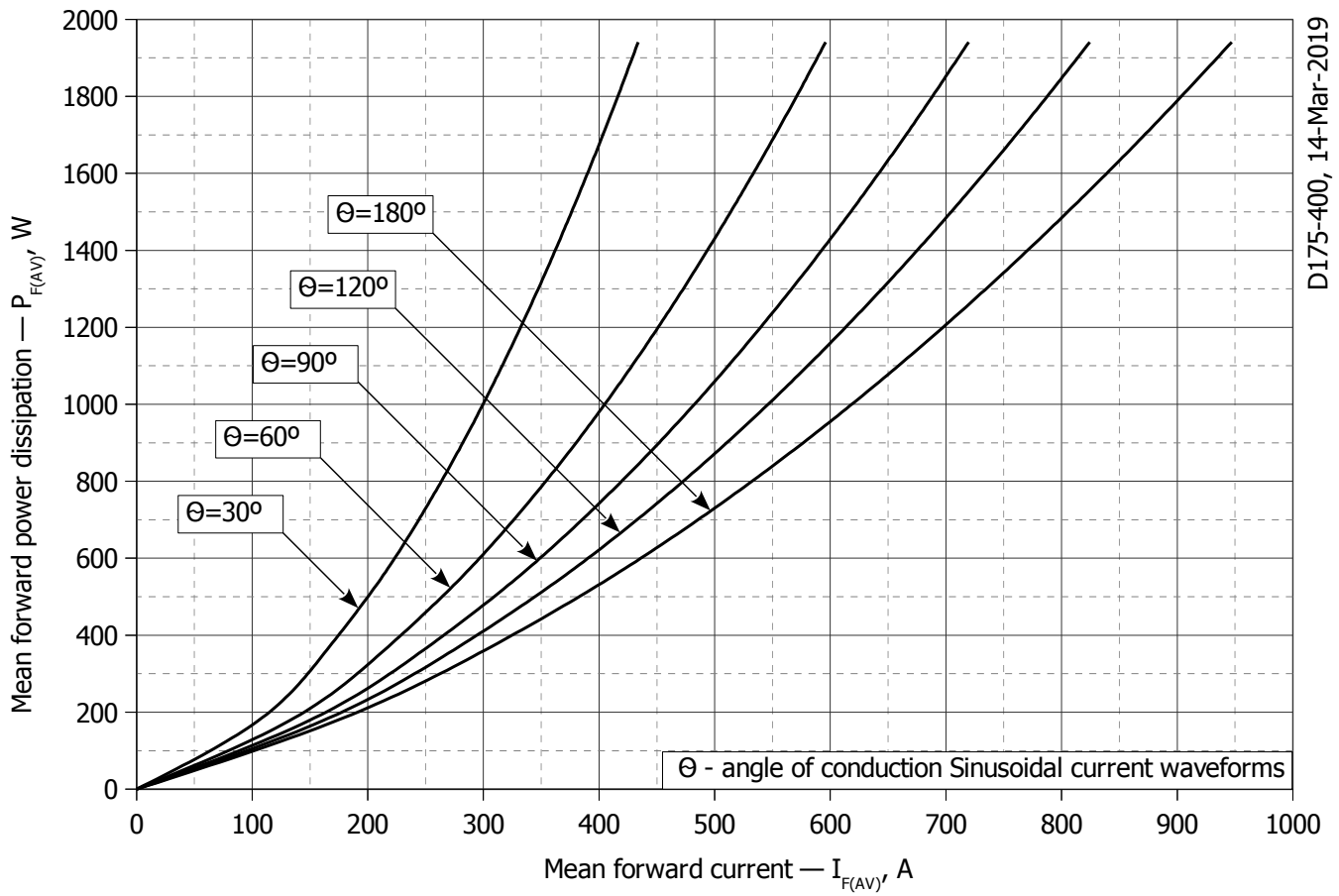


Fig. 7 - Mean forward power dissipation P_{FAV} vs. mean forward current I_{FAV} for sinusoidal current waveforms at different conduction angles ($f=50\text{Hz}$, DSC)

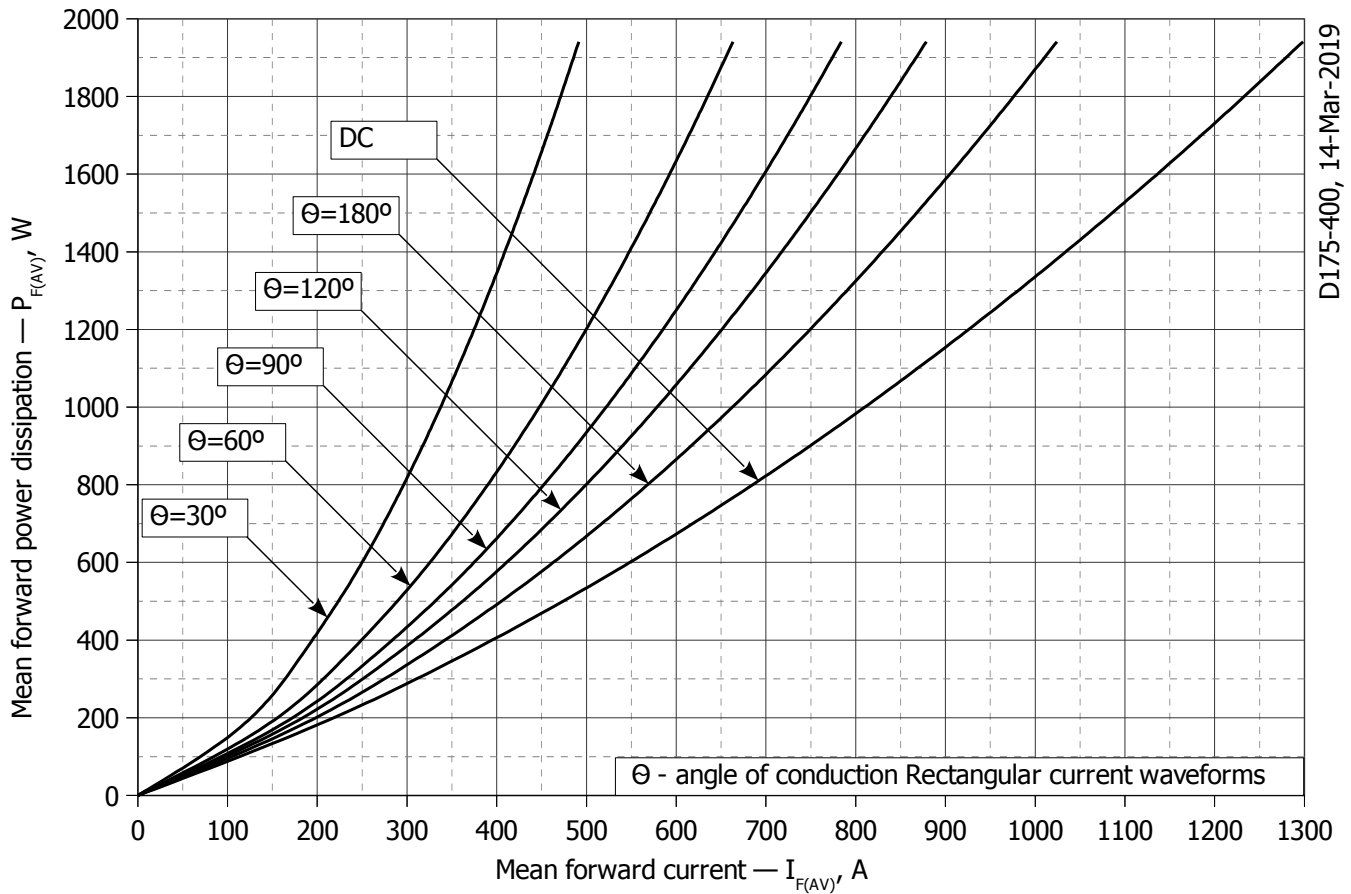
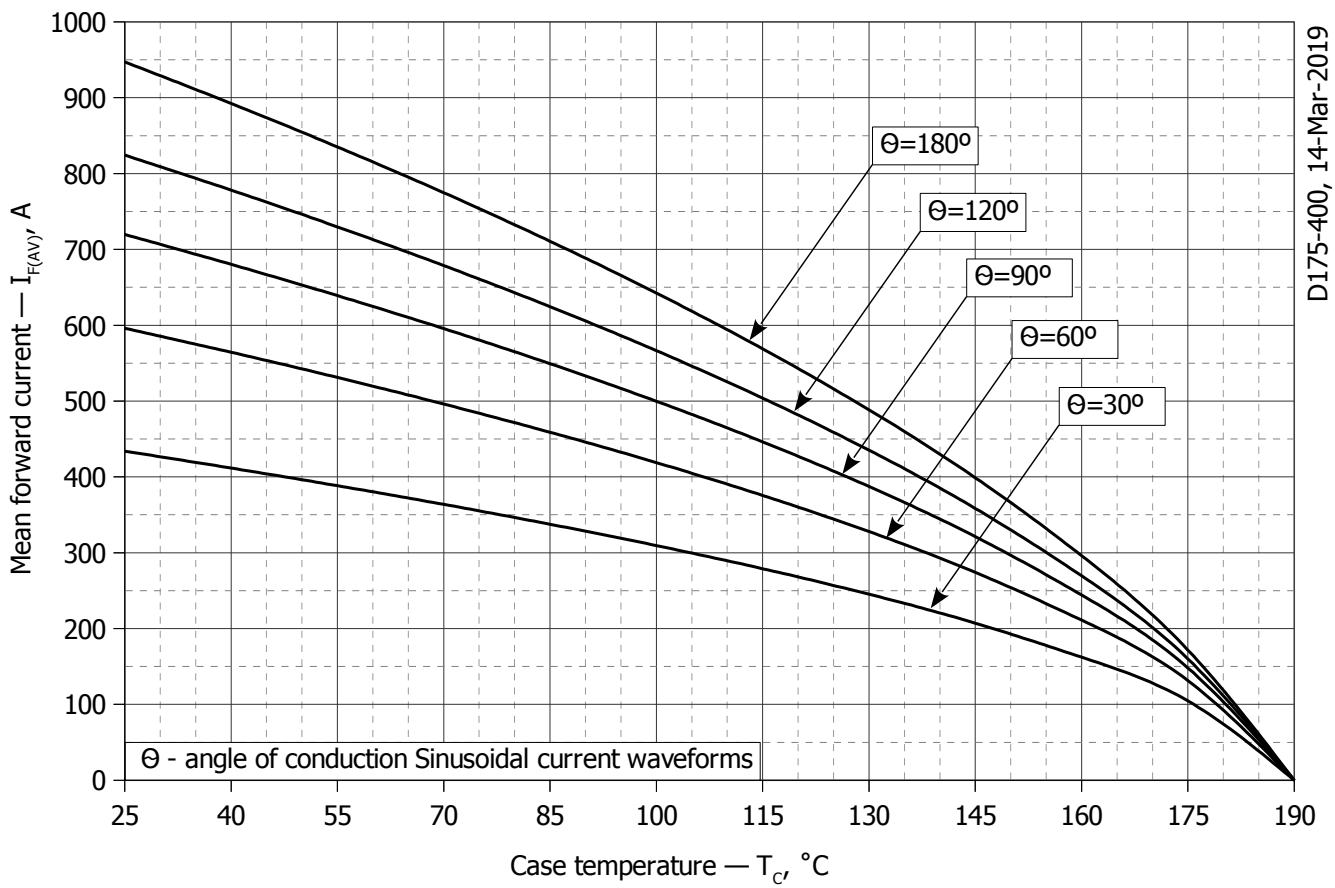
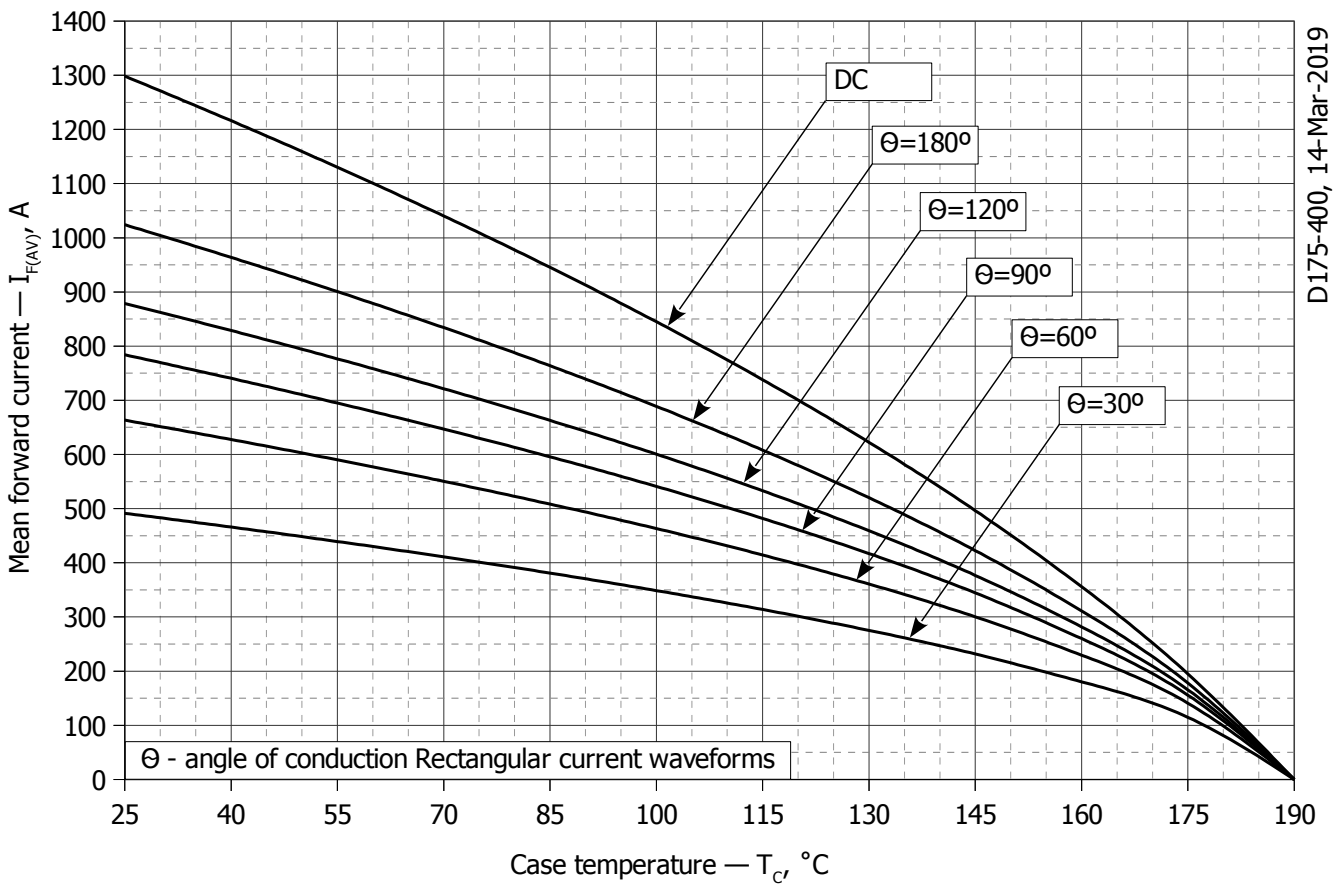


Fig. 8 - Mean forward power dissipation P_{FAV} vs. mean forward current I_{FAV} for rectangular current waveforms at different conduction angles and for DC ($f=50\text{Hz}$, DSC)



D175-400, 14-Mar-2019

Fig. 9 – Mean forward current I_{FAV} vs. case temperature T_c for sinusoidal current waveforms at different conduction angles ($f=50\text{Hz}$, DSC)



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Fig. 10 - Mean forward current I_{FAV} vs. case temperature T_c for rectangular current waveforms at different conduction angles and for DC ($f=50\text{Hz}$, DSC)

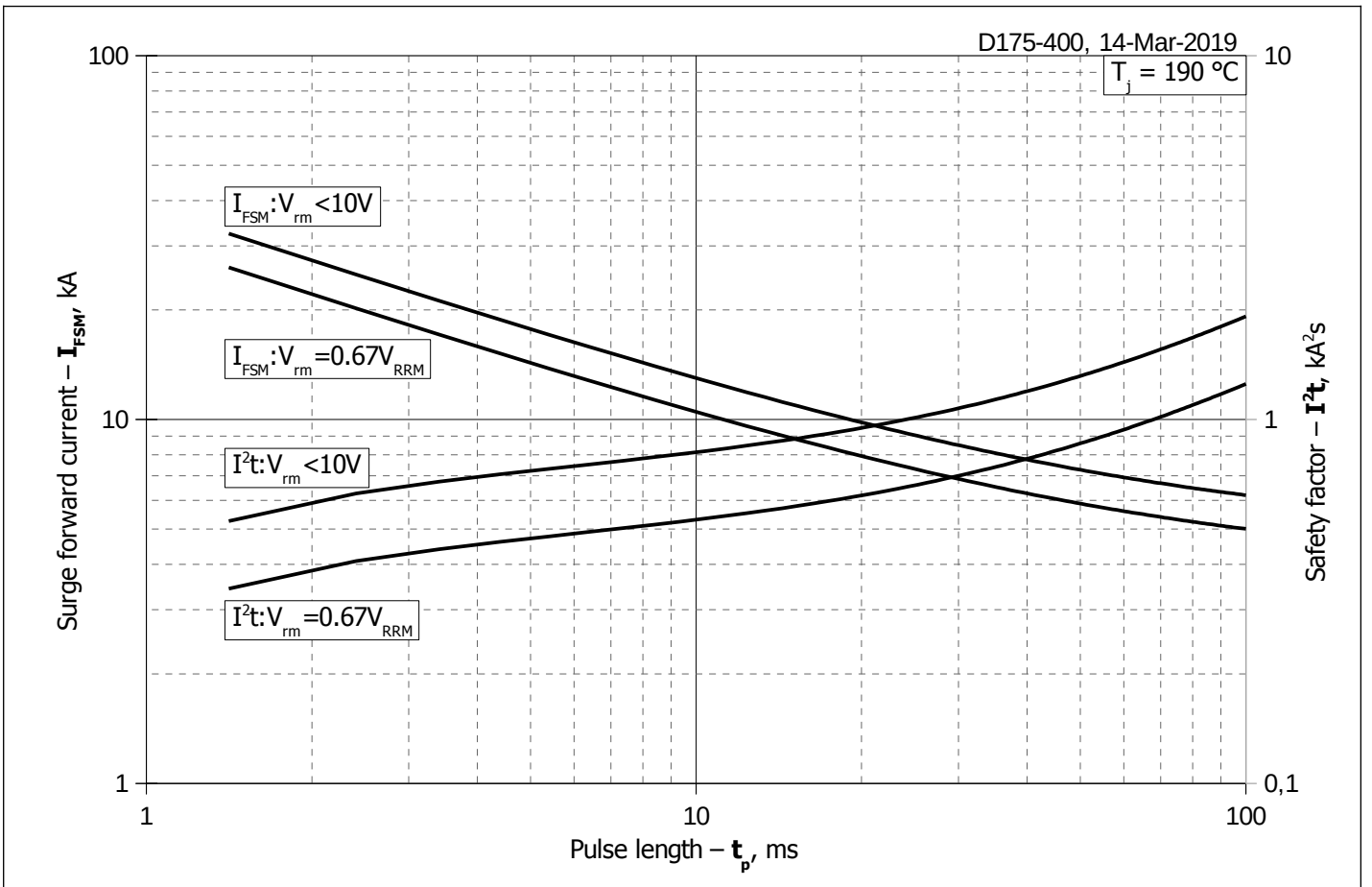


Fig. 11 – Maximum surge forward current I_{FSM} and safety factor I^2t vs. pulse length t_p

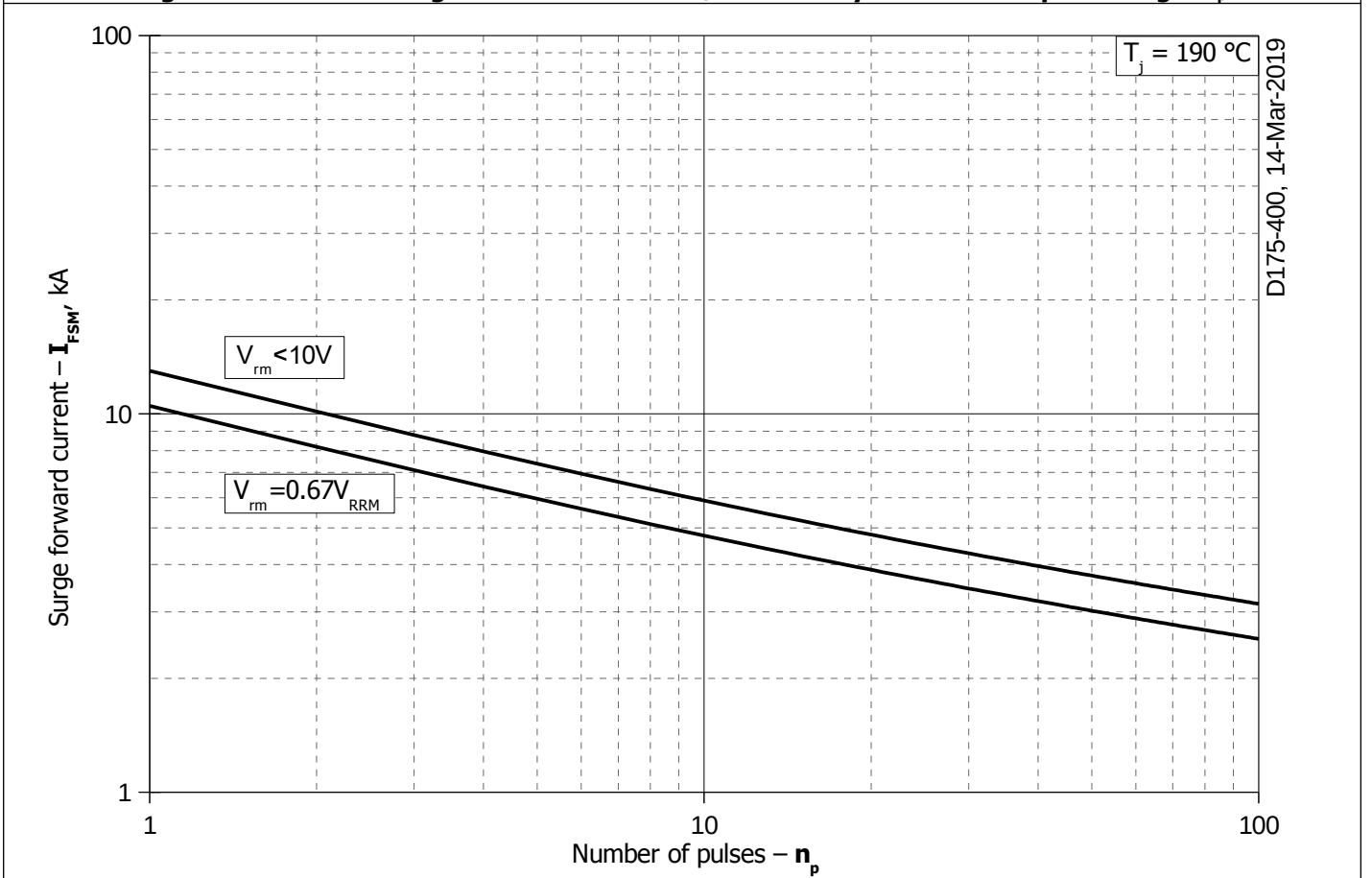


Fig. 12 - Maximum surge forward current I_{FSM} vs. number of pulses n_p